

2SC4466

Silicon NPN Triple Diffused Planar Transistor (Complement to type 2SA1693)

Application : Audio and General Purpose

Absolute maximum ratings (Ta=25°C)

Symbol	2SC4466	Unit
V _{CB0}	120	V
V _{CEO}	80	V
V _{EB0}	6	V
I _C	6	A
I _B	3	A
P _C	60(T _C =25°C)	W
T _J	150	°C
T _{stg}	-55 to +150	°C

Electrical Characteristics (Ta=25°C)

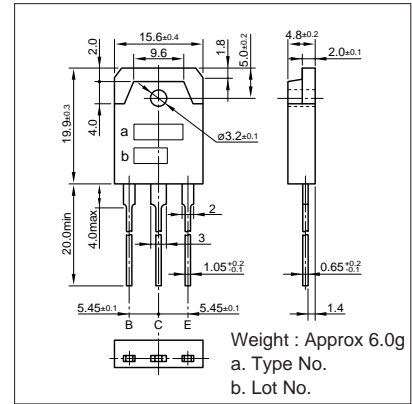
Symbol	Conditions	2SC4466	Unit
I _{CB0}	V _{CB} =120V	10max	μA
I _{EB0}	V _{EB} =6V	10max	μA
V(BR) _{CEO}	I _C =50mA	80min	V
h _{FE}	V _{CE} =4V, I _C =2A	50min*	
V _{CE(sat)}	I _C =2A, I _B =0.2A	1.5max	V
f _r	V _{CE} =12V, I _E =-0.5A	20typ	MHz
COB	V _{CB} =10V, f=1MHz	110typ	pF

*h_{FE} Rank O(50to100), P(70to140), Y(90to180)

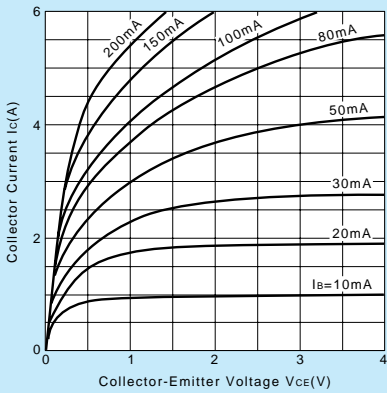
Typical Switching Characteristics (Common Emitter)

V _{CC} (V)	R _L (Ω)	I _C (A)	V _{BB1} (V)	V _{BB2} (V)	I _{B1} (A)	I _{B2} (A)	t _{on} (μs)	t _{stg} (μs)	t _f (μs)
30	10	3	10	-5	0.3	-0.3	0.16typ	2.60typ	0.34typ

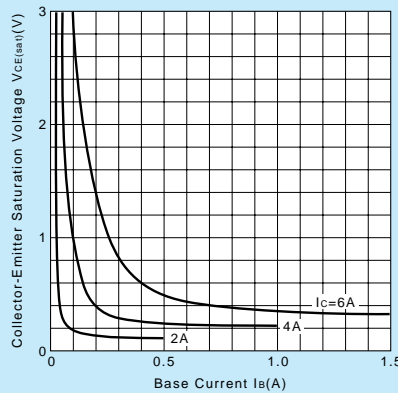
External Dimensions MT-100(TO3P)



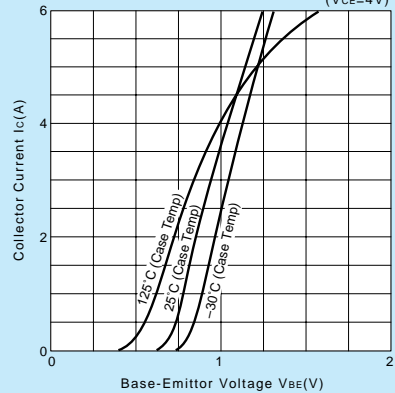
I_C-V_{CE} Characteristics (Typical)



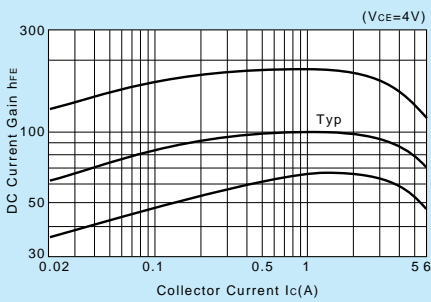
V_{CE(sat)}-I_B Characteristics (Typical)



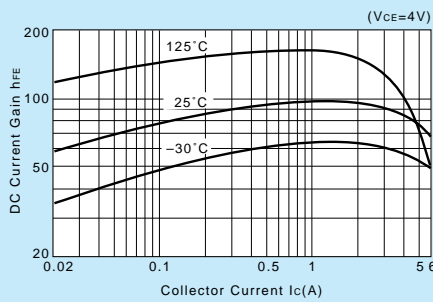
I_C-V_{BE} Temperature Characteristics (Typical)



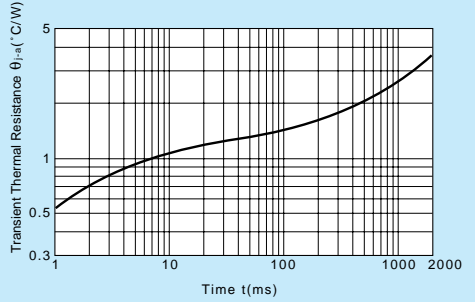
h_{FE}-I_C Characteristics (Typical)



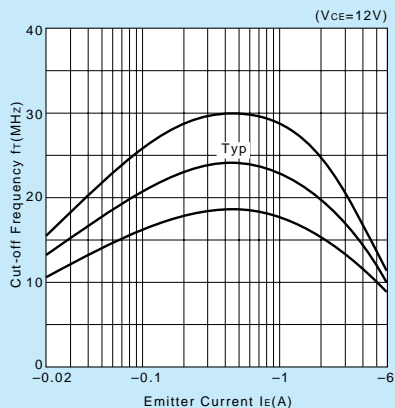
h_{FE}-I_C Temperature Characteristics (Typical)



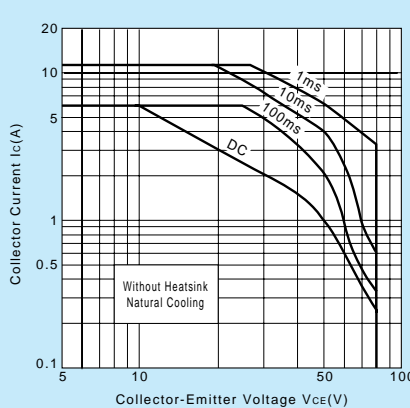
θ_{j-a}-t Characteristics



f_r-I_E Characteristics (Typical)



Safe Operating Area (Single Pulse)



P_C-T_a Derating

